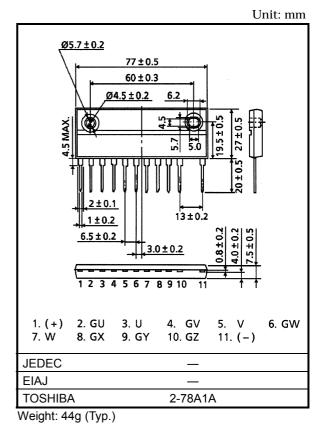
TOSHIBA GTR Module Silicon N Channel IGBT

# MP6754

High Power Switching Applications Motor Control Applications

- The electrodes are isolated from case.
- 6 IGBTs are built into 1 package.
- Enhancement-mode
- Low saturation voltage
  - : VCE (sat) = 4.0V (Max) (IC = 10A)
- High speed :  $t_f = 0.35 \mu s$  (Max) (IC = 10A)  $t_{rr} = 0.15 \mu s$  (Max) (IF = 10A)



### **Equivalent Circuit**

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#### Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Collector-emitter voltage		V <sub>CES</sub>	600	V	
Gate-emitter voltage		V <sub>GES</sub>	± 20	V	
Collector current	DC	Ι <sub>C</sub>	10	A	
	1ms	I <sub>CP</sub>	20		
Forward current	DC	١ <sub>F</sub>	10	A	
	1ms	I <sub>FM</sub>	20		
Collector power dissipation (Tc = 25°C)		P <sub>C</sub>	40	W	
Junction temperature		Тј	150	°C	
Storage temperature range		T <sub>stg</sub>	-40 ~ 125	°C	
Isolation voltage		V <sub>ISOL</sub>	2500 (AC 1 minute)	V	
Screw torque		—	1.5	N∙m	

#### **Electrical Characteristics (Ta = 25°C)**

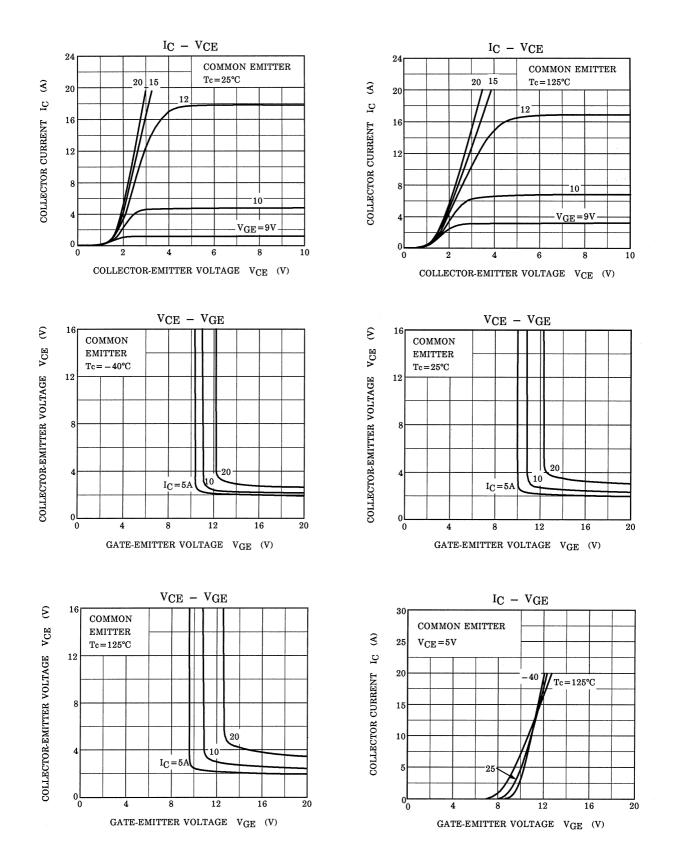
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GES</sub>	$V_{GE} = \pm 20V, V_{CE} = 0$	_	_	± 500	nA
Collector cut-off current		ICES	V <sub>CE</sub> = 600V, V <sub>GE</sub> = 0	_	_	1.0	mA
Gate-emitter cut-off voltage		V <sub>GE (off)</sub>	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 5V	6.0	_	9.0	V
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 10A, V <sub>GE</sub> = 15V	—	3.0	4.0	V
Input capacitance		Cies	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0, f = 1MHz	—	620	_	pF
Switching time	Rise time	tr		—	0.3	0.6	- µs
	Turn-on time	t <sub>on</sub>		_	0.4	0.8	
	Fall time	t <sub>f</sub>		_	0.2	0.35	
	Turn-off time	t <sub>off</sub>		_	0.4	0.8	
Forward voltage		V <sub>F</sub>	I <sub>F</sub> = 10A, V <sub>GE</sub> = 0	_	1.7	2.5	V
Reverse recovery time		t <sub>rr</sub>	I <sub>F</sub> = 10A, V <sub>GE</sub> = −10V di / dt = 100A / μs	_	0.08	0.15	μs
Thermal resistance		R <sub>th (j-c)</sub>	Transistor	— — 3.09		°C/W	
			Diode	_	—	3.09	0/10

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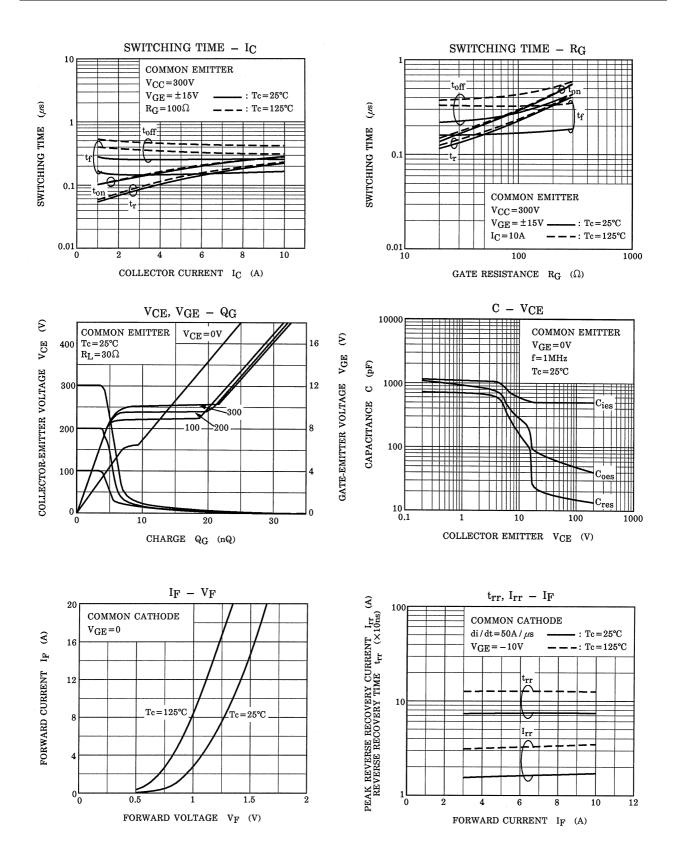
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